

General purpose transistor (isolated transistors)

EMD30

DTB713Z □ and DTC114E □ A are housed independently in a EMT6 package.

●Applications

DC / DC converter
Motor driver

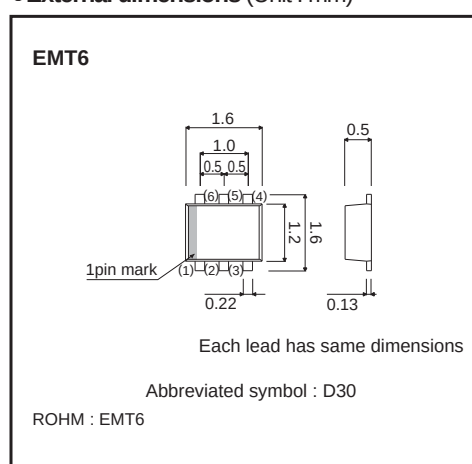
●Features

- 1) DTr₁ : PNP digital transistor
DTr₂ : NPN digital transistor
- 2) Mounting possible with EMT3 automatic mounting machines.

●Structure

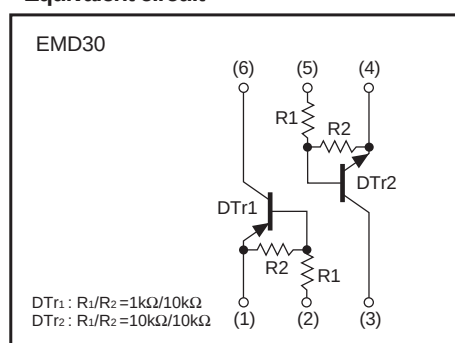
PNP / NPN Silicon epitaxial planar digital transistor

●External dimensions (Unit : mm)



The following characteristics apply to both DTr₁ and DTr₂.

●Equivalent circuit



●Packaging specifications

Type	EMD30
Package	EMT6
Marking	D30
Code	T2R
Basic ordering unit (pieces)	8000

Transistors

●Absolute maximum ratings (Ta=25°C)

DTr1

Parameter	Symbol	DTr1	Unit
Supply voltage	V _{CC}	−30	V
Input voltage	V _{IN}	−10 to +5	V
Output current	I _{C (MAX.)}	−200	mA
Power dissipation	P _d	120	mW *
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	−55 to +150	°C

* Each terminal mounted on a recommended.

DTr2

Parameter	Symbol	DTr2	Unit
Supply voltage	V _{CC}	50	V
Input voltage	V _{IN}	−10 to +40	V
Output current	I _o	50	mA
	I _{C (MAX.)}	100	
Power dissipation	P _d	120	mW *
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	−55 to +150	°C

* Each terminal mounted on a recommended.

DTr1/DTr2

Parameter	Symbol	Limits	Unit
Power dissipation	P _d	150(TOTAL)	mW *
Storage temperature	T _{stg}	−55 to +125	°C

* Each terminal mounted on a recommended.

Transistors

●Electrical characteristics (Ta=25°C)

DTr1

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	—	—	−0.3	V	$V_{CC} = -5V$ / $I_o = -100\mu A$
	$V_{I(on)}$	−2.5	—	—	V	$V_o = -0.3V$ / $I_o = -20mA$
Output voltage	$V_{O(on)}$	—	−70	−300	mV	$I_o = -50mA$, $I_i = -2.5mA$
Input current	I_i	—	—	−6.4	mA	$V_i = -5V$
Output current	$I_{O(off)}$	—	—	−0.5	μA	$V_{CC} = -30V$ / $V_i = 0V$
DC current gain	G_i	140	—	—	—	$V_o = -2V$ / $I_o = -100mA$
Transition frequency	f_T	—	260	—	MHz	$V_{CE} = -10V$ / $I_E = 5mA$, $f = 100MHz$
Input resistance	R_1	0.7	1.0	1.3	$k\Omega$	—
Resistance ratio	R_2/R_1	8	10	12	—	—

* Characteristics of built-in transistor.

DTr2

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	—	—	0.5	V	$V_{CC} = 5V$ / $I_o = 100\mu A$
	$V_{I(on)}$	3	—	—	V	$V_o = 0.3V$ / $I_o = 2mA$
Output voltage	$V_{O(on)}$	—	100	300	mV	$I_o = 10mA$, $I_i = 0.5mA$
Input current	I_i	—	—	880	μA	$V_i = 5V$
Output current	$I_{O(off)}$	—	—	0.5	μA	$V_{CC} = 50V$ / $V_i = 0V$
DC current gain	G_i	30	—	—	—	$V_o = 5V$ / $I_o = 5mA$
Transition frequency	f_T	—	250	—	MHz	$V_{CE} = 10V$ / $I_E = -5mA$, $f = 100MHz$
Input resistance	R_1	7	10	13	$k\Omega$	—
Resistance ratio	R_2/R_1	0.8	1	1.2	—	—

* Characteristics of built-in transistor.

Transistors

●Electrical characteristic curves

DTr1

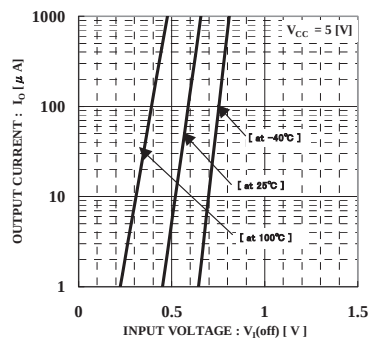


Fig.1 Output current vs. input voltage (OFF characteristics)

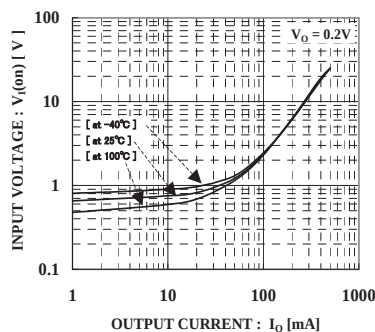


Fig.2 Input voltage vs. output current (ON characteristics) I

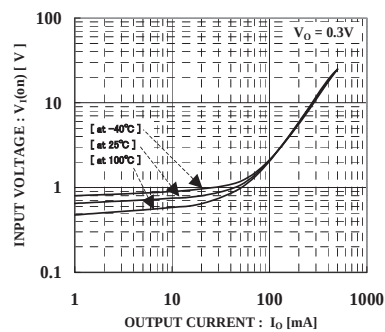


Fig.3 Input voltage vs. output current (ON characteristics) II

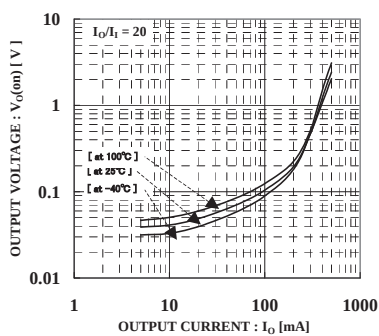


Fig.4 Output voltage vs. output current I

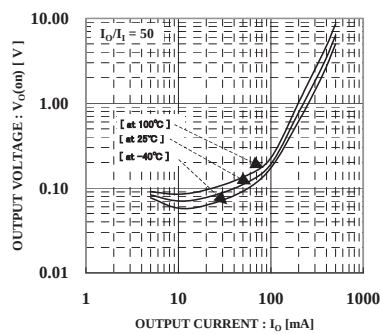


Fig.5 Output voltage vs. output current II

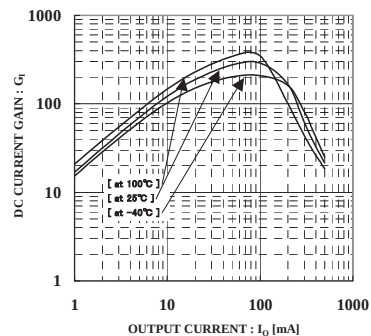


Fig.6 DC current gain vs. output current

Transistors

DTr2

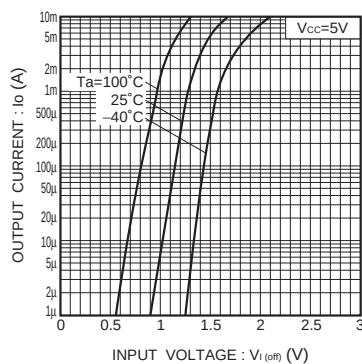


Fig.7 Output current vs. input voltage (OFF characteristics)

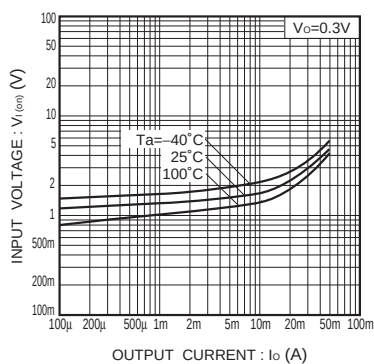


Fig.8 Input voltage vs. output current (ON characteristics)

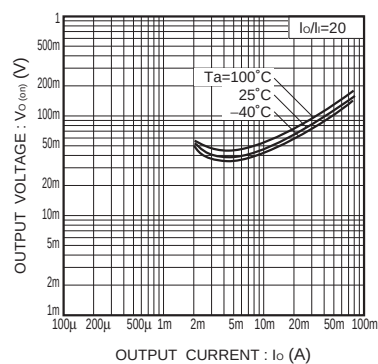


Fig.9 Output voltage vs. output current

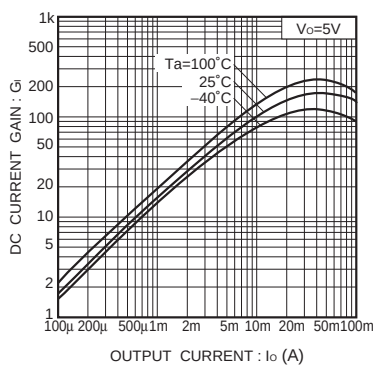


Fig.10 DC current gain vs. output current

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